

N CHANNEL MOSFET, 60V, 10.6A, POWER 56, FULL REEL, Transistor Polarity:N Channel, Continuous Drain Current Id:10.6A, Drain Source Voltage Vds:60V, On Resistance Rds(on):0.0094ohm, Rds(on) Test Voltage Vgs:20V



Images are for reference only

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	DFN8
Product Type	Transistors
RoHS	Green
Lifecycle	

Please submit RFQ for FDMS5672 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

UltraFET devices combine characteristics that enable benchmark efficiency in power conversion applications. Optimized for rDS(on), low ESR, low total and Miller gate charge, these devices are ideal for high frequency DC to DC converters.

## Features

Typ = 10 V

## Application

ONSEMI

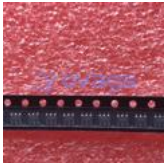


## Related Products



### [FDC645N](#)

ON Semiconductor, LLC  
SSOT-6



### [FDC6305N](#)

ON Semiconductor, LLC  
SSOT-6



### [FDD8647L](#)

ON Semiconductor, LLC  
TO-252-3



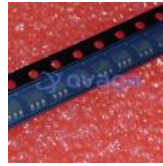
### [FDD5N50NZTM](#)

ON Semiconductor, LLC  
TO-252



### [FDC637BNZ](#)

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### [FDC602P](#)

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### [FDD3670](#)

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